BC807-16L, BC807-25L, BC807-40L

General Purpose Transistors

PNP Silicon

Features

- S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant



Rating	Symbol	Value	Unit
Collector – Emitter Voltage	V _{CEO}	-45	V
Collector – Base Voltage	V _{CBO}	-50	V
Emitter – Base Voltage	V _{EBO}	-5.0	V
Collector Current – Continuous	Ι _C	-500	mAdc

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board, (Note 1) T _A = 25°C Derate above 25°C	P _D	225 1.8	mW mW/°C
Thermal Resistance, Junction-to-Ambient	R_{\thetaJA}	556	°C/W
Total Device Dissipation Alumina Substrate, (Note 2) T _A = 25°C Derate above 25°C	PD	300 2.4	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	417	°C/W
Junction and Storage Temperature	T _J , T _{stg}	-55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

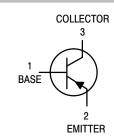
1. $FR-5 = 1.0 \times 0.75 \times 0.062$ in.

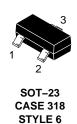
2. Alumina = 0.4 x 0.3 x 0.024 in 99.5% alumina.



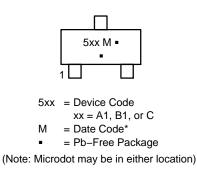
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MARKING DIAGRAM



*Date Code orientation and/or overbar may vary depending upon manufacturing location.

ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted.)

Characteristic		Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					-	
Collector – Emitter Breakdown Voltage $(I_C = -10 \text{ mA})$		V _{(BR)CEO}	-45	-	-	V
Collector – Emitter Breakdown Voltage $(V_{EB} = 0, I_C = -10 \ \mu A)$		V _{(BR)CES}	-50	-	-	V
Emitter – Base Breakdown Voltage $(I_E = -1.0 \ \mu A)$		V _{(BR)EBO}	-5.0	-	-	V
Collector Cutoff Current $(V_{CB} = -20 \text{ V})$ $(V_{CB} = -20 \text{ V}, \text{ T}_{J} = 150^{\circ}\text{C})$		I _{CBO}			-100 -5.0	nA μA
ON CHARACTERISTICS						
DC Current Gain (I _C = -100 mA, V _{CE} = -1.0 V) (I _C = -500 mA, V _{CE} = -1.0 V)	BC807–16, SBC80–16L BC807–25, SBC807–25L BC807–40, SBC807–40L	h _{FE}	100 160 250 40	- - -	250 400 600 -	_
Collector – Emitter Saturation Voltage $(I_C = -500 \text{ mA}, I_B = -50 \text{ mA})$		V _{CE(sat)}	-	-	-0.7	V
Base – Emitter On Voltage ($I_C = -500 \text{ mA}, V_{CE} = -1.0 \text{ V}$)		V _{BE(on)}	-	_	-1.2	V
SMALL-SIGNAL CHARACTERISTICS						
Current-Gain – Bandwidth Product (I _C = -10 mA, V _{CE} = -5.0 Vdc, f = 100 MHz)		f _T	100	-	-	MHz
		1	1	1	1	

Output Capacitance
 $(V_{CB} = -10 \text{ V}, \text{ f} = 1.0 \text{ MHz})$ Cobo-10-pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

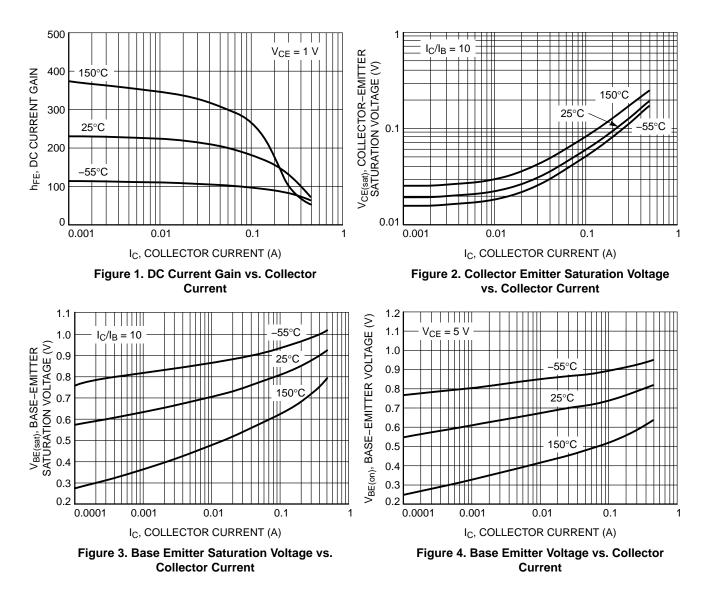
ORDERING INFORMATION

Device	Specific Marking	Package	Shipping [†]		
BC807-16LT1G	544		3000 / Tape & Reel		
SBC807-16LT1G*	5A1				
BC807-16LT3G	544		40.000 / Tana & Deal		
SBC807-16LT3G*	5A1		10,000 / Tape & Reel		
BC807-25LT1G	5B1	SOT-23 (Pb-Free)	2000 / Tana & Daal		
SBC807-25LT1G*	001		3000 / Tape & Reel		
BC807-25LT3G	5B1		10,000 / Tape & Reel		
SBC807-25LT3G*	361				
BC807-40LT1G	5C		3000 / Tape & Reel		
SBC807-40LT1G*	50				
BC807-40LT3G	5C		10,000 / Tape & Reel		
SBC807-40LT3G*	50		10,0007 Tape & Reef		

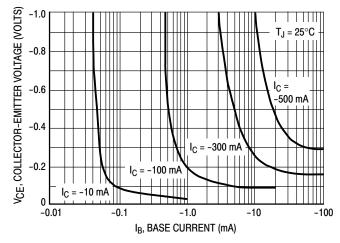
+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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TYPICAL CHARACTERISTICS – BC807–16LT1



TYPICAL CHARACTERISTICS – BC807–16LT1





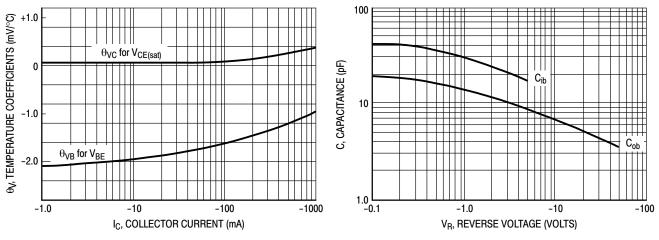
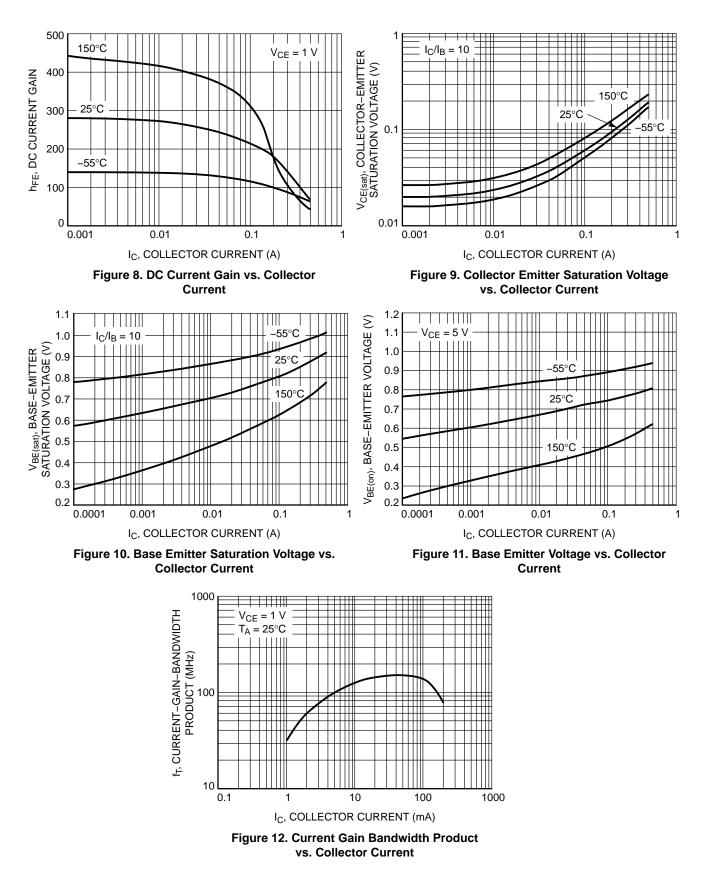


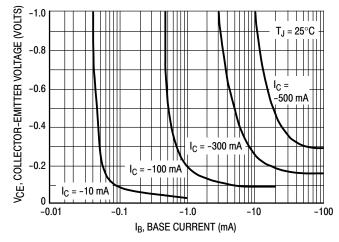
Figure 6. Temperature Coefficients

Figure 7. Capacitances

TYPICAL CHARACTERISTICS – BC807–25LT1



TYPICAL CHARACTERISTICS – BC807–25LT1





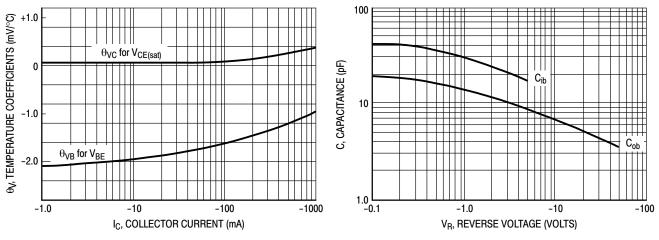
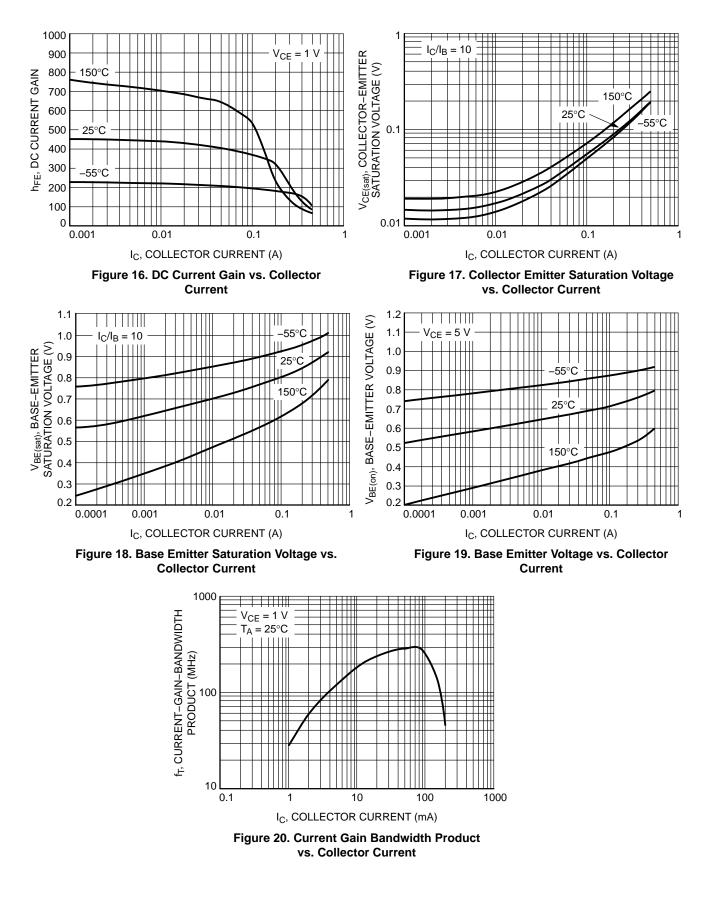


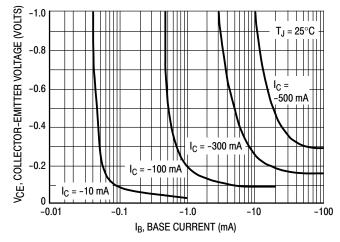
Figure 14. Temperature Coefficients

Figure 15. Capacitances

TYPICAL CHARACTERISTICS – BC807–40LT1



TYPICAL CHARACTERISTICS – BC807–40LT1





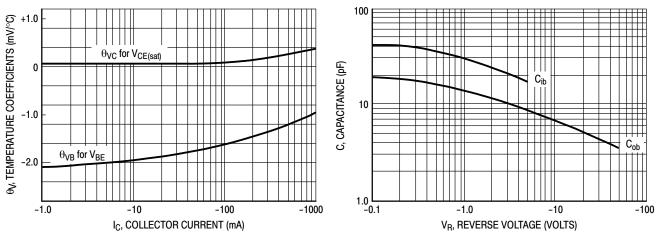
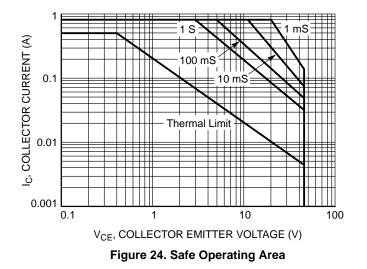


Figure 22. Temperature Coefficients

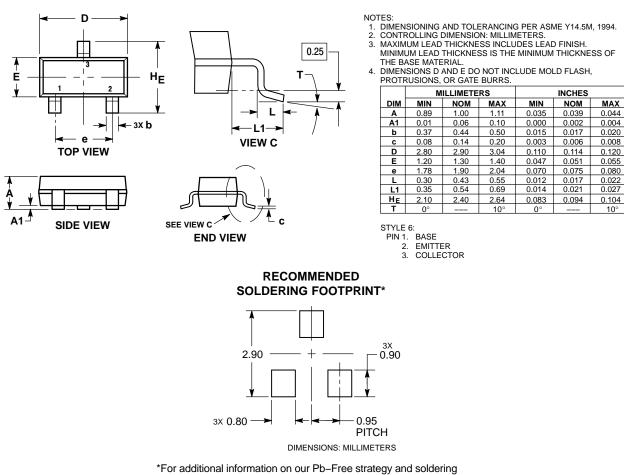
Figure 23. Capacitances

TYPICAL CHARACTERISTICS - BC807-16LT1, BC807-25LT1, BC807-40LT1



PACKAGE DIMENSIONS

SOT-23 (TO-236) CASE 318-08 ISSUE AR



For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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